ON Semiconductor

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MPSA18

Preferred Device

Low Noise Transistor

NPN Silicon

Features

• These are Pb-Free Devices*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V _{CEO}	45	Vdc
Collector - Base Voltage	V _{CBO}	45	Vdc
Emitter-Base Voltage	V _{EBO}	6.5	Vdc
Collector Current – Continuous	Ic	200	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

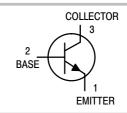
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

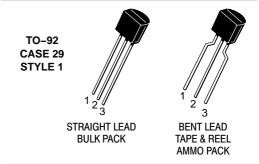
1. $R_{\theta JA}$ is measured with the device soldered into a typical printed circuit board.



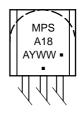
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MARKING DIAGRAM



A = Assembly Location

Y = Year WW = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MPSA18G	TO-92 (Pb-Free)	5000 Units / Bulk
MPSA18RLRAG	TO-92 (Pb-Free)	2000/Tape & Reel
MPSA18RLRMG	TO-92 (Pb-Free)	2000/Ammo Pack

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

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^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (Note 2) $(I_C = 10 \text{ mAdc}, I_B = 0)$	V _{(BR)CEO}	45	_	-	Vdc
Collector – Base Breakdown Voltage ($I_C = 100 \mu Adc, I_E = 0$)	V _{(BR)CBO}	45	_	_	Vdc
Emitter–Base Breakdown Voltage ($I_E = 10 \mu Adc, I_C = 0$)	V _{(BR)EBO}	6.5	_	_	Vdc
Collector Cutoff Current (V _{CB} = 30 Vdc, I _E = 0)	Ісво	_	1.0	50	nAdc
ON CHARACTERISTICS (Note 2)					
DC Current Gain	h _{FE}	400 500 500 500	580 850 1100 1150	- - - 1500	-
Collector – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}$, $I_B = 0.5 \text{ mAdc}$) ($I_C = 50 \text{ mAdc}$, $I_B = 5.0 \text{ mAdc}$)	V _{CE(sat)}	- -	- 0.08	0.2 0.3	Vdc
Base – Emitter On Voltage (I _C = 1.0 mAdc, V _{CE} = 5.0 Vdc)	V _{BE(on)}	-	0.6	0.7	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current–Gain – Bandwidth Product (I _C = 1.0 mAdc, V _{CE} = 5.0 Vdc, f = 100 MHz)	f _T	100	160	-	MHz
Collector–Base Capacitance (V _{CB} = 5.0 Vdc, I _E = 0, f = 1.0 MHz)	C _{cb}	_	1.7	3.0	pF
Emitter-Base Capacitance (V _{EB} = 0.5 Vdc, I _C = 0, f = 1.0 MHz)	C _{eb}	-	5.6	6.5	pF
Noise Figure $ \begin{array}{l} \text{Noise Figure} \\ \text{(I}_{C}=100~\mu\text{Adc, V}_{CE}=5.0~\text{Vdc, R}_{S}=10~\text{k}\Omega,f=1.0~\text{kHz)} \\ \text{(I}_{C}=100~\mu\text{Adc, V}_{CE}=5.0~\text{Vdc, R}_{S}=1.0~\text{k}\Omega,f=100~\text{Hz)} \end{array} $	NF	- -	0.5 4.0	1.5 -	dB
Equivalent Short Circuit Noise Voltage (I _C = 100 μ Adc, V _{CE} = 5.0 Vdc, R _S = 1.0 k Ω , f = 100 Hz)	V _T	-	6.5	-	nV/√ Hz

^{2.} Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

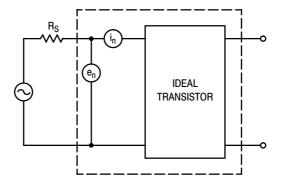


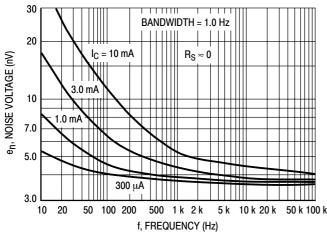
Figure 1. Transistor Noise Model

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NOISE CHARACTERISTICS

 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}C)$

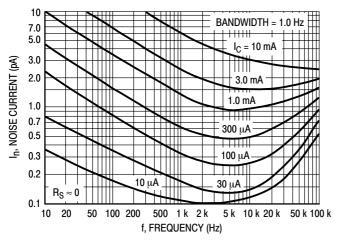
NOISE VOLTAGE



BANDWIDTH = 1.0 Hz 20 $R_S \approx 0\,$ en, NOISE VOLTAGE (nV) f = 10 Hz 10 7.0 5.0 3.0 0.01 0.02 0.1 0.2 0.5 1.0 2.0 5.0 0.05 10 IC, COLLECTOR CURRENT (mA)

Figure 2. Effects of Frequency

Figure 3. Effects of Collector Current



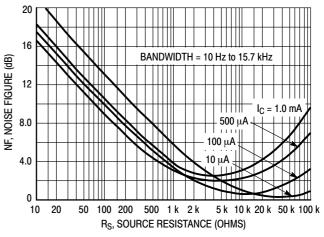
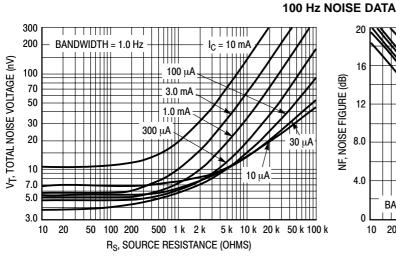


Figure 4. Noise Current

Figure 5. Wideband Noise Figure



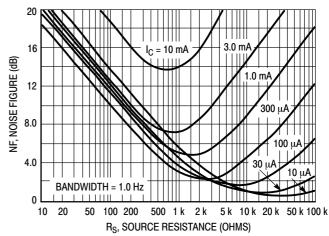


Figure 6. Total Noise Voltage

Figure 7. Noise Figure

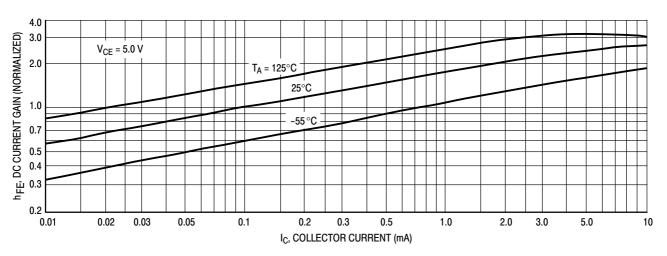


Figure 8. DC Current Gain

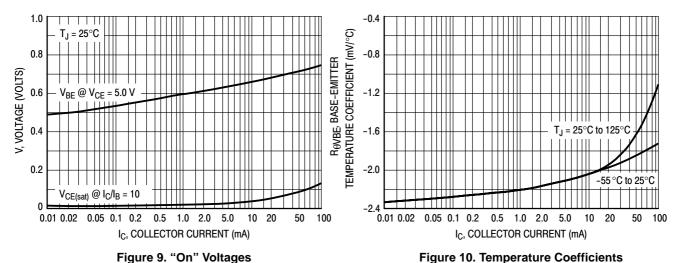


Figure 9. "On" Voltages

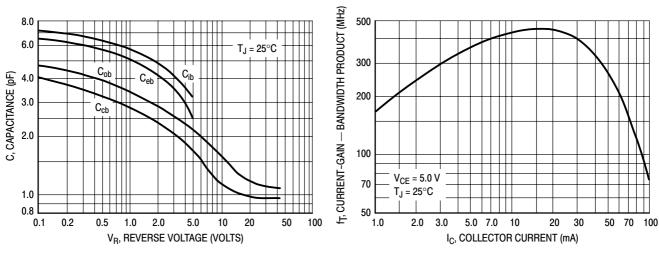


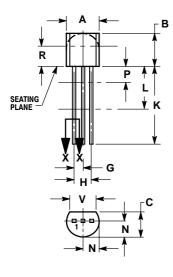
Figure 11. Capacitance

Figure 12. Current-Gain - Bandwidth Product

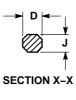
MPSA18

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AM**



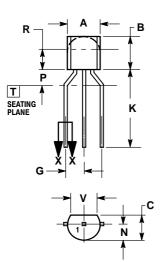
STRAIGHT LEAD **BULK PACK**



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	



BENT LEAD TAPE & REEL AMMO PACK



NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
 CONTOUR OF PACKAGE BEYOND
- DIMENSION R IS UNCONTROLLED
- LEAD DIMENSION IS UNCONTROLLED IN PAND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS		
DIM	MIN MAX		
Α	4.45	5.20	
В	4.32	5.33	
С	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
J	0.39	0.50	
K	12.70		
N	2.04	2.66	
P	1.50	4.00	
R	2.93		
V	3.43		

STYLE 1:

PIN 1 FMITTER

BASE

COLLECTOR

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